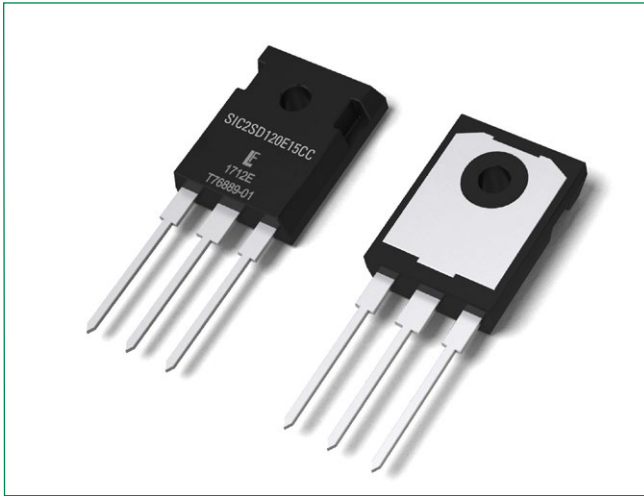


LSIC2SD120E15CC



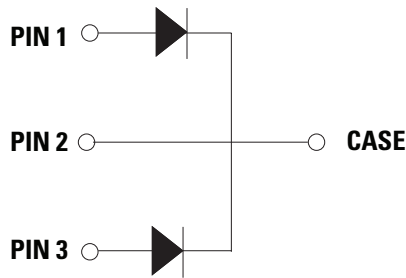
**Description**

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

**Features**

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

**Circuit Diagram TO247-3L**



**Applications**

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

**Environmental**

- Littelfuse "RoHS" logo = RoHS conform
- Littelfuse "HF" logo = Halogen Free
- Littelfuse "PB-free" logo = Pb-free lead plating

**Maximum Ratings**

Characteristics	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	-	1200	V
DC Blocking Voltage	$V_R$	$T_J = 25\text{ °C}$	1200	V
Continuous Forward Current (Per Leg/Device)	$I_F$	$T_C = 25\text{ °C}$	24.5/49	A
		$T_C = 135\text{ °C}$	12/24	
		$T_C = 154\text{ °C}$	8/16	
Non-Repetitive Forward Surge Current (Per Leg)	$I_{FSM}$	$T_C = 25\text{ °C}, T_p = 10\text{ ms}, \text{Half sine pulse}$	65	A
Power Dissipation (Per Leg/Device)	$P_{Tot}$	$T_C = 25\text{ °C}$	125/250	W
		$T_C = 110\text{ °C}$	54/108	
Operating Junction Temperature	$T_J$	-	-55 to 175	°C
Storage Temperature	$T_{STG}$	-	-55 to 150	°C
Soldering Temperature	$T_{sold}$	-	260	°C

**Electrical Characteristics (Per Leg)**

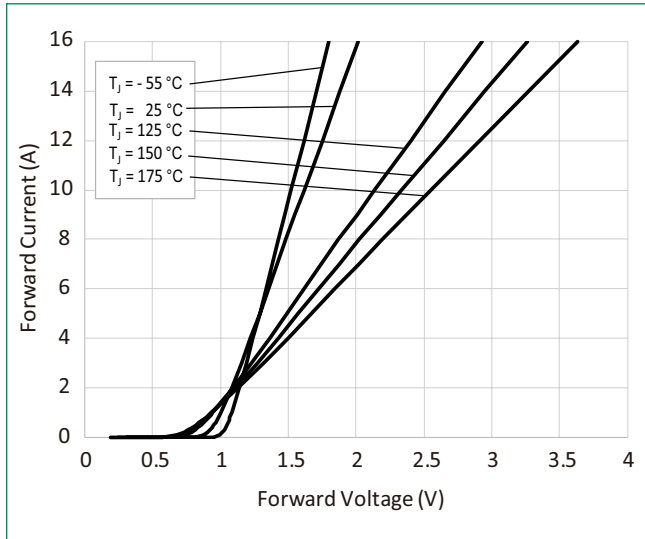
Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Forward Voltage	$V_F$	$I_F = 8\text{ A}, T_J = 25\text{ }^\circ\text{C}$	-	1.5	1.8	V
		$I_F = 8\text{ A}, T_J = 175\text{ }^\circ\text{C}$	-	2.2	-	
Reverse Current	$I_R$	$V_R = 1200\text{ V}, T_J = 25\text{ }^\circ\text{C}$	-	<1	100	$\mu\text{A}$
		$V_R = 1200\text{ V}, T_J = 175\text{ }^\circ\text{C}$	-	10	-	
Total Capacitance	C	$V_R = 1\text{ V}, f = 1\text{ MHz}$	-	454	-	pF
		$V_R = 400\text{ V}, f = 1\text{ MHz}$	-	45	-	
		$V_R = 800\text{ V}, f = 1\text{ MHz}$	-	33	-	
Total Capacitive Charge	$Q_C$	$V_R = 800\text{ V}, Q_C = \int_0^{V_R} C(V)dV$	-	47	-	nC

Footnote:  $T_J = +25\text{ }^\circ\text{C}$  unless otherwise specified

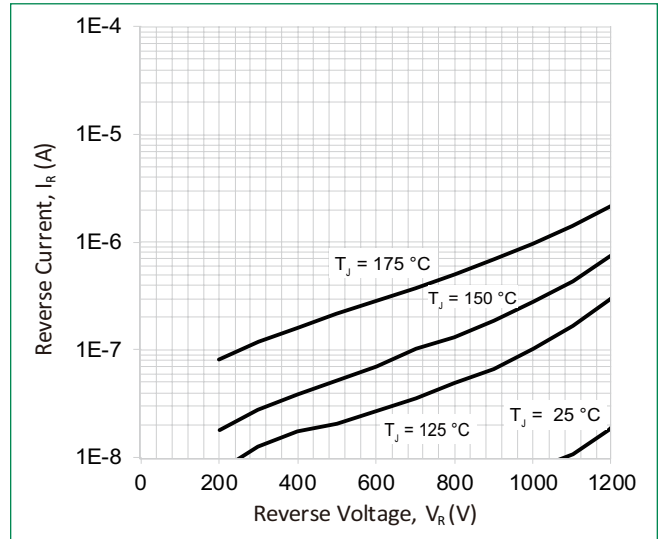
**Thermal Characteristics**

Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Thermal Resistance (Per Device/Leg)	$R_{\theta JC}$	-	-	1.2/0.6	-	$^\circ\text{C/W}$

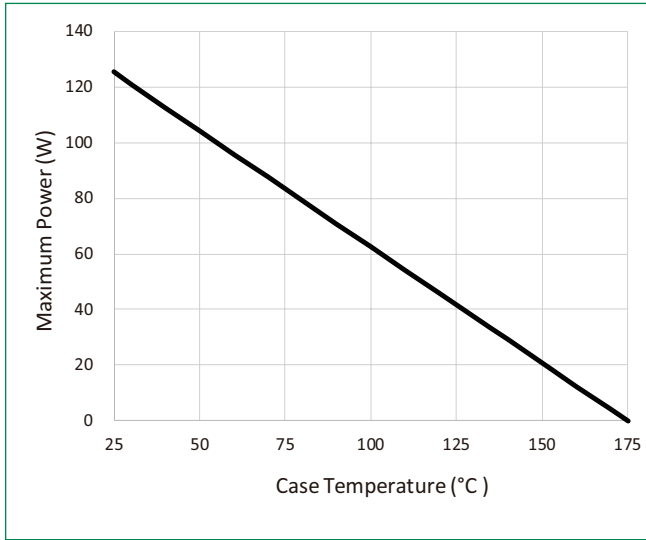
**Figure 1: Typical Forward Characteristics (Per Leg)**



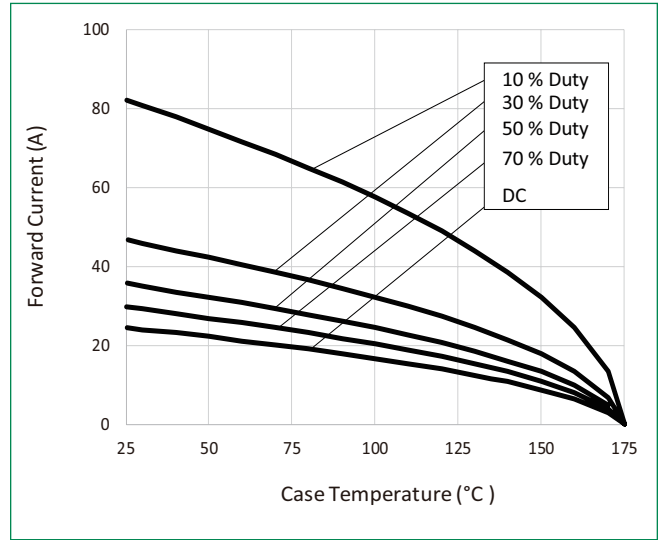
**Figure 2: Typical Reverse Characteristics (Per Leg)**



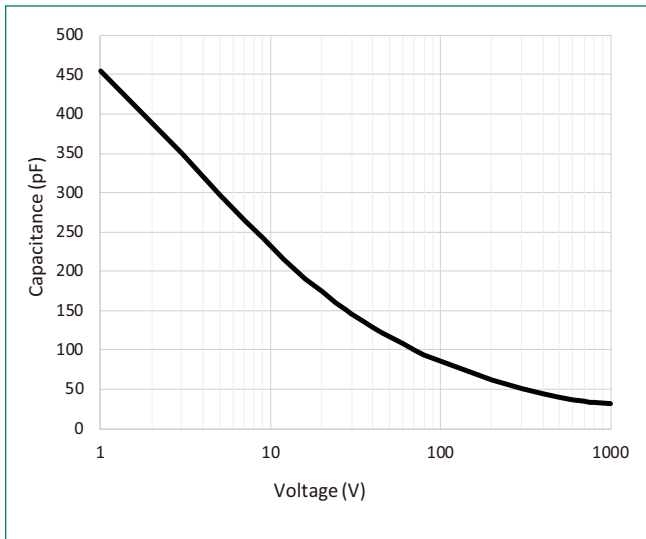
**Figure 3: Power Derating (Per Leg)**



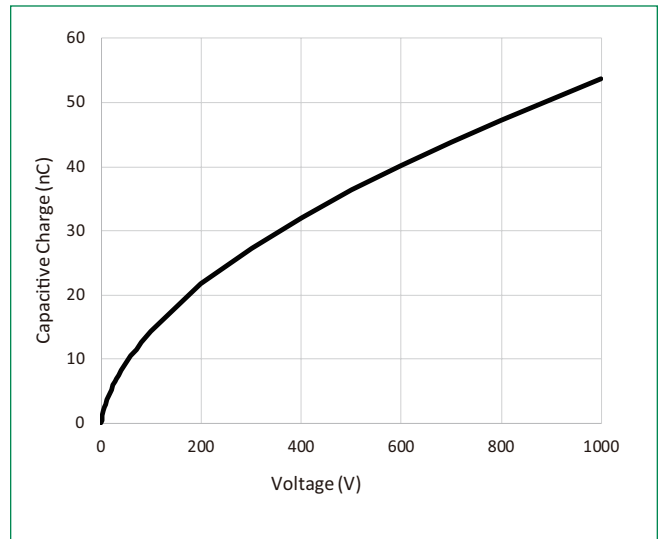
**Figure 4: Current Derating (Per Leg)**



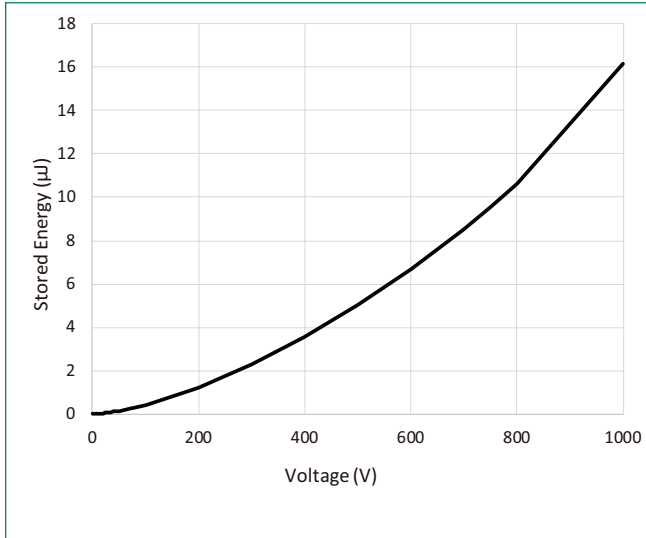
**Figure 5: Capacitance vs. Reverse Voltage (Per Leg)**



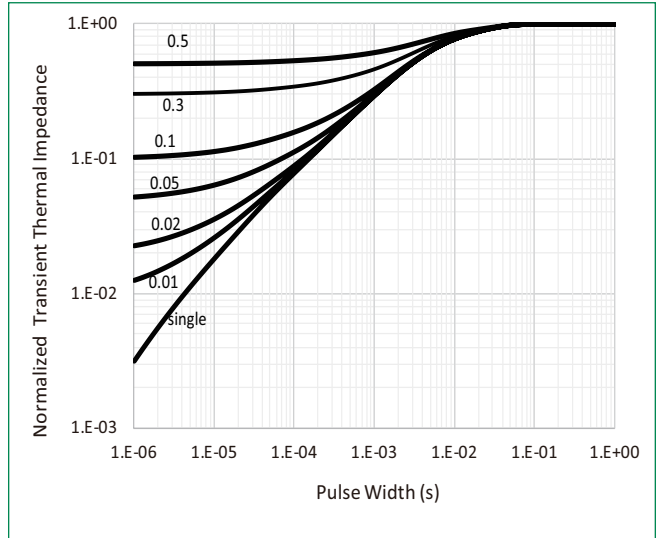
**Figure 6: Capacitive Charge vs. Reverse Voltage (Per Leg)**



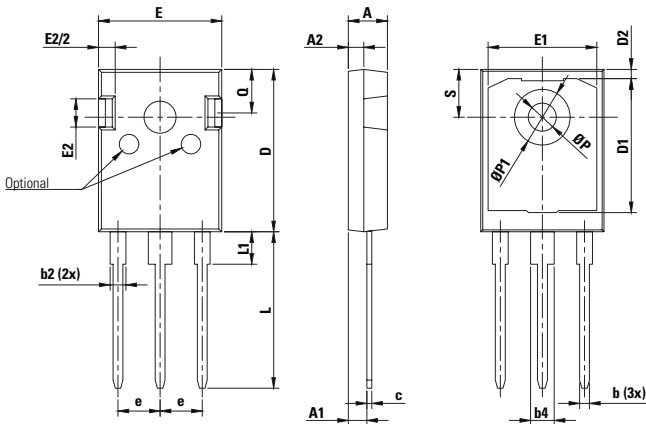
**Figure 7: Stored Energy vs. Reverse Voltage (Per Leg)**



**Figure 8: Transient Thermal Impedance (Per Device)**

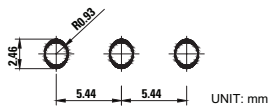


**Package Dimensions TO-247-3L**



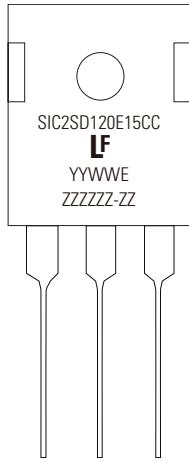
Symbol	Millimeters		
	Min	Nom	Max
A	4.80	5.03	5.20
A1	2.25	2.38	2.54
A2	1.85	1.98	2.11
b	0.99	-	1.40
b2	1.65	-	2.39
b4	2.59	-	3.43
c	0.38	0.64	0.89
D	20.80	20.96	21.34
D1	13.50	-	-
D2	0.51	1.19	1.35
e	5.44 BSC		
E	15.75	15.90	16.13
E1	13.06	14.02	14.15
E2	4.19	4.32	4.83
L	19.81	20.19	20.57
L1	3.81	4.19	4.45
øP	3.55	3.61	3.66
øP1	7.06	7.19	7.32
Q	5.49	5.61	6.20
S	6.05	6.17	6.30

**Recommended Hole Pattern Layout**



- Notes:**
- Dimensions are in millimeters
  - Dimension D, E do not include mold flash. Mold flash shall not exceed 0.127 mm per side measured at outer most extreme of plastic body.
  - øP to have a maximum draft angle of 38.1 mm to the top of the part with a maximum hole diameter of 3.912 mm.

**Part Numbering and Marking System**

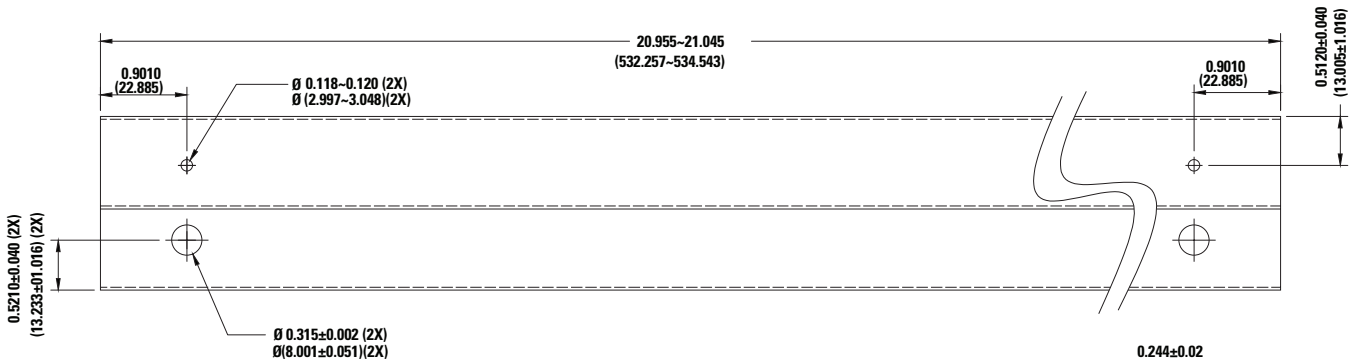


- SIC = SiC
- 2 = Gen2
- SD = Schottky Diode
- 120 = Voltage Rating (1200 V)
- E = TO-247-3L
- 15 = Current Rating ( 15 A)
- CC = Common Cathode
- YY = Year
- WW = Week
- E = Special Code
- ZZZZZZ-ZZ = Lot Number

**Packing Options**

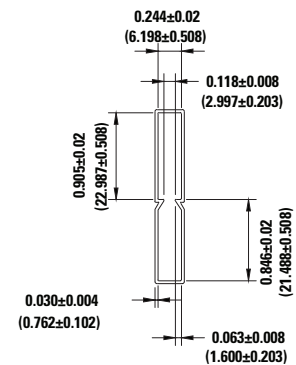
Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD120E15CC	SIC2SD120E15CC	Tube (30pcs)	450

**Packing Specification TO-247-3L**



**NOTE:**

1. All pin plug holes are considered critical dimension
2. Tolerance is to be ±0.010 unless otherwise specified
3. Dimension are in inch (and millimeters).



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